

Optical properties of perovskite alkaline-earth titanates: a formulation

This article has been downloaded from IOPscience. Please scroll down to see the full text article.

2002 J. Phys.: Condens. Matter 14 3849

(<http://iopscience.iop.org/0953-8984/14/15/301>)

View [the table of contents for this issue](#), or go to the [journal homepage](#) for more

Download details:

IP Address: 171.66.16.104

The article was downloaded on 18/05/2010 at 06:27

Please note that [terms and conditions apply](#).

Optical properties of perovskite alkaline-earth titanates: a formulation

Kamal Krishna Saha¹, Tanusri Saha-Dasgupta¹, Abhijit Mookerjee¹,
Sonali Saha² and T P Sinha²

¹ S N Bose National Centre for Basic Sciences, Block-JD, Sector-III, Kolkata-700098, India

² Department of Physics, J C Bose Institute, 93/1 Acharya Prafulla Chandra Road,
Kolkata-700009, India

E-mail: kamal@bose.res.in

Received 21 December 2001, in final form 5 March 2002

Published 4 April 2002

Online at stacks.iop.org/JPhysCM/14/3849

Abstract

In this communication we suggest a formulation of the optical conductivity as a convolution of an energy-resolved joint density of states and an energy–frequency labelled transition rate. Our final aim is to develop a scheme based on the augmented space recursion for random systems. In order to gain confidence in our formulation, we apply the formulation to three alkaline-earth titanates, CaTiO₃, SrTiO₃ and BaTiO₃, and compare our results with available data on optical properties of these systems.

1. Introduction

The object of our present study is to derive an expression for the optical conductivity as a convolution of the energy-resolved joint density of states and an energy–frequency dependent transition rate. The need is to go beyond the usual reciprocal space based formulations and obtain an expression which we can immediately generalize for disordered systems. This would require labelling states by energy and the angular momentum labels (ℓ, m) alone. Once we derive this expression we shall find a representation for the optical conductivity in the minimal basis set of the tight-binding linearized muffin-tin orbitals (TB-LMTO). The generalization to disordered systems will be carried out through the augmented-space recursion (ASR) introduced by us earlier for the study of electronic properties of disordered systems [1–5]. The ASR carries out the configuration averaging essential to the description of properties of disordered systems, going beyond the usual mean-field approaches and taking into account configuration fluctuations. The input into the ASR method includes the Hamiltonian parameters of the pure constituents, as the starting point of the local spin-density approximation (LSDA) iterations for the alloy. It also includes the information about the transition rates of the pure constituents, expressed as functions of the initial- and final-state energies. The aim of this paper is to reformulate the reciprocal-space representation of the transition rate and re-express

it in the energy–frequency labelled representation for the pure constituents. Only when we are confident that this works can we proceed with the full calculations for the disordered alloy. This communication is an attempt to verify our formulation for a series of alkaline-earth titanates in the paraelectric phase, on which extensive theoretical and experimental data as regards optical properties are available for comparison.

The perovskite structured titanate ferroelectric compound has been, to date, one of the most extensively investigated materials. Such compounds are extremely interesting from the viewpoint of solid-state theoreticians because their structures are a lot simpler than those of any other ferroelectric material known and, therefore, they prove to be rather simple systems to study in order to better understand the ferroelectric phenomenon. The titanates are very easily prepared as polycrystalline ceramics; they are chemically and mechanically fairly stable and they exhibit a paraelectric-to-ferroelectric phase transition at or above room temperature. Continued interest in these compounds has led to a wide variety of theoretical and experimental work, especially on lattice vibrations. A less common approach has been that based on electronic structure calculations [6]. Michel-Calendini and Mesnard [7, 8] have reported the band structure of BaTiO₃ within a linear combination of atomic orbitals (LCAO) method with empirical off-diagonal integrals. The pioneering work on SrTiO₃ was that of Kahn and Leyendecker [9]. This was followed by an augmented-plane-wave (APW) calculation by Mattheiss [10] and a self-consistent tight-binding calculation by Soules *et al* [11]. However, Battaye *et al* [12] have compared experimental valence band spectra with these early theoretical predictions and have concluded that the agreement was not satisfactory. Pertosa and Michel-Calendini [13] carried out a modified tight-binding calculation on BaTiO₃ and SrTiO₃ and compared their results with x-ray photoelectron spectra. These authors introduced inner orbital interactions. Perkins and Winter [14] have carried out LCAO calculations on the band structure of SrTiO₃. There have been several all-electron, full-potential linearized augmented-plane-wave (FP-LAPW) studies of the titanates in recent times [17–19]. In addition, studies based on the ultrasoft-pseudopotential local density approximation (LDA) on perovskites have been carried out by King-Smith and Vanderbilt [20]. In comparison, electronic structure calculations on CaTiO₃ have been fewer. Ueda *et al* [25, 26] have used the first-principles tight-binding method to study CaTiO₃.

We shall show that for all three compounds the transition rate, defined by us, is strongly energy and frequency dependent, i.e. it depends upon the energy of both the initial and the final states. We shall compare the theoretical results with experiment.

2. Methodology

In recent years a number of methods have been proposed for calculating optical properties within the framework of the LMTO [27–32] for both metals and semiconductors. We shall present here a gauge-independent formalism, following the ideas of Hobbs *et al* [32]. Since our final aim is to use the ASR method [1–5] to study the optical properties of random systems, we shall modify the reciprocal-space formulation and obtain an expression in which all states are labelled by their energy and the optical conductivity is expressed as a convolution of the energy-resolved joint density of states and an energy–frequency dependent transition matrix. This formulation will then be directly generalized within the ASR.

The Hamiltonian describing the effect of a radiation field on the electronic states of a solid is given by

$$H = \sum_{i=1}^N \left\{ \frac{1}{2m_e} \left(\mathbf{p}_i + \frac{e}{c} \mathbf{A}(\mathbf{r}_i, t) \right)^2 + V(\mathbf{r}_i) + e\Phi(\mathbf{r}_i, t) \right\}.$$

Here e is the magnitude of the electronic charge, m_e is the electronic mass, c is the velocity of light and \hbar is Planck's constant. $\mathbf{A}(\mathbf{r}_i, t)$ and $\Phi(\mathbf{r}_i, t)$ are the vector and scalar potentials seen by the i th electron because of the radiation field. There are N electrons labelled by i . The potential $V(\mathbf{r}_i)$ experienced by the electrons is expressed in an effective independent-electron approximation within the LDA of the density functional theory (DFT). For not-too-large external optical fields, neglecting terms of the order of $|\mathbf{A}|^2$, the Hamiltonian reduces to

$$H = \sum_{i=1}^N \left\{ \frac{1}{2m_e} \mathbf{p}_i^2 + V(\mathbf{r}_i) + \frac{1}{c} \mathbf{j}_i \cdot \mathbf{A}(\mathbf{r}_i, t) \right\}. \quad (1)$$

Here $\mathbf{j}_i = (e/m)\mathbf{p}_i$ is the current operator. We work in the Coulomb gauge where $\nabla \cdot \mathbf{A}(\mathbf{r}_i, t) = 0$ and $\Phi(\mathbf{r}_i, t) = 0$, so the electric field

$$\mathbf{E}(\mathbf{r}_i, t) = -\frac{\partial \mathbf{A}(\mathbf{r}_i, t)}{\partial t}.$$

In choosing the above equation we have ignored the response of the system. The local electric field is made up of the external field due to the incident radiation as well as the internal field due to the polarization of the medium. Such local field corrections are important for insulators. We intend, as is customary, to introduce the local field corrections as well as corrections due to the Coulomb hole in our final GW calculations, for which the single-particle picture will form the zeroth starting point.

The Kubo formula then relates the linear current response to the radiation field:

$$\langle j_\mu(t) \rangle = \sum_\nu \int_{-\infty}^{\infty} dt' \chi_{\mu\nu}(t-t') A_\nu(t').$$

The generalized susceptibility is given by

$$\chi_{\mu\nu}(\tau) = i\Theta(\tau) \langle \phi_0 | [j_\mu(\tau), j_\nu(0)] | \phi_0 \rangle$$

where $\tau = t - t'$ and $\Theta(\tau)$ is the Heaviside step function:

$$\Theta(\tau) = \begin{cases} 1 & \text{if } \tau > 0 \\ 0 & \text{if } \tau \leq 0. \end{cases}$$

$|\phi_0\rangle$ is the ground state of the unperturbed system—that is, the solid in the absence of the radiation field. In the absence of the radiation field, there is no photocurrent, i.e. $\langle \phi_0 | j_\mu | \phi_0 \rangle = 0$. The fluctuation-dissipation theorem relates the imaginary part of the generalized susceptibility to the correlation function as follows:

$$\chi''_{\mu\nu}(\omega) = \frac{1}{2}(1 - e^{-\beta\hbar\omega}) S_{\mu\nu}(\omega) \quad (2)$$

where

$$\beta = \frac{1}{k_B T}$$

where k_B is the Boltzmann constant and T the temperature and

$$\chi''_{\mu\nu}(\omega) = \text{Im} \int_{-\infty}^{\infty} dt e^{iz\tau} \chi_{\mu\nu}(\tau) \quad z = \omega + i0^+$$

and

$$S_{\mu\nu}(\omega) = \text{Im} \int_{-\infty}^{\infty} dt e^{iz\tau} \langle \phi_0 | j_\mu(\tau) j_\nu(0) | \phi_0 \rangle \quad z = \omega + i0^+.$$

An expression for the correlation function can be obtained via the Kubo–Greenwood expression:

$$S(\omega) = \frac{\pi}{3} \sum_i \sum_f \sum_\mu \langle \phi_i | j_\mu | \phi_f \rangle \langle \phi_f | j_\mu | \phi_i \rangle \delta(E_f - E_i - \hbar\omega). \quad (3)$$

We have assumed isotropy of the response so that the tensor $S_{\mu\nu}$ is diagonal and we have defined $S(\omega)$ as the direction averaged quantity $\frac{1}{3} \sum_\mu S_{\mu\mu}(\omega)$. The $|\{\phi_i\}\rangle$ are the occupied ‘initial’ single-electron states in the ground state while $|\{\phi_f\}\rangle$ are the unoccupied single-electron ‘final’ excited states in the LDA description.

The imaginary part of the dielectric function is related to the above:

$$\varepsilon_2(\omega) = \frac{1}{\pi^2 \omega^2} S(\omega). \quad (4)$$

We may obtain the real part of the dielectric function $\varepsilon_1(\omega)$ from a Kramers–Krönig relationship.

For crystalline semiconductors the equation (3) may be rewritten as follows:

$$S(\omega) = \frac{\pi}{3} \sum_j \sum_{j'} \int_{BZ} \frac{d^3\mathbf{k}}{8\pi^3} |\langle \Phi_{j'\mathbf{k}} | j | \Phi_{j\mathbf{k}} \rangle|^2 \delta(E_{j'}(\mathbf{k}) - E_j(\mathbf{k}) - \hbar\omega). \quad (5)$$

Here j and j' refer to band labels: j for the occupied valence bands and j' the unoccupied conduction bands at $T = 0$ K. \mathbf{k} is the quantum label associated with the Bloch theorem. For disordered materials, the Bloch theorem fails and the expression (5) can no longer be used. Our first aim will be to obtain an alternative expression where the quantum states are directly labelled by energy and frequency, rather than by the ‘band’ and ‘crystal momentum’ indices. To this end, let us examine the following expressions:

$$n(E) = \sum_j \int_{BZ} \frac{d^3\mathbf{k}}{8\pi^3} \delta(E_j(\mathbf{k}) - E) \quad (6)$$

$$J(E, \omega) = \sum_j \sum_{j'} \int_{BZ} \frac{d^3\mathbf{k}}{8\pi^3} \delta(E_j(\mathbf{k}) - E) \delta(E_{j'}(\mathbf{k}) - E - \hbar\omega). \quad (7)$$

In equation (6), the right-hand side picks up a factor of 1 whenever a quantum state, labelled by $\{\mathbf{k}, j\}$ falls in the range $E, E + \delta E$. The left-hand side, therefore, is the *density of states* arising from the bands labelled j .

In equation (7), the right-hand side picks up a factor of 1 whenever a quantum state in the filled bands labelled j falls in the range $E, E + \delta E$ and *simultaneously* a quantum state in the unfilled bands labelled j' falls in the range $E + \omega, E + \omega + \delta E$. The left-hand side is then the *energy-resolved joint density of states*:

$$J(E, \omega) = n_v(E) n_c(E + \hbar\omega). \quad (8)$$

We shall define the energy–frequency labelled *transition rate* as

$$T(E, \omega) = \frac{\sum_j \sum_{j'} \int_{BZ} (d^3\mathbf{k}/8\pi^3) T^{jj'}(\mathbf{k}) \delta(E_j(\mathbf{k}) - E) \delta(E_{j'}(\mathbf{k}) - E - \hbar\omega)}{\sum_j \sum_{j'} \int_{BZ} (d^3\mathbf{k}/8\pi^3) \delta(E_j(\mathbf{k}) - E) \delta(E_{j'}(\mathbf{k}) - E - \hbar\omega)} \quad (9)$$

where

$$T^{jj'}(\mathbf{k}) = \sum_\mu |\langle \Phi_{j'\mathbf{k}} | j_\mu | \Phi_{j\mathbf{k}} \rangle|^2.$$

The expression for $S(\omega)$ from equation (5) then becomes

$$S(\omega) = (\pi/3) \int dE T(E, \omega) J(E, \omega). \quad (10)$$

Many earlier workers argued that the transition matrix element is weakly dependent on both E and ω . They then assumed it to be constant, T_0 , and obtained a simple expression for the correlation function:

$$S_0(\omega) = (\pi/3)T_0 \int dE J(E, \omega). \quad (11)$$

We shall investigate the validity of this approximation for the systems under study in this communication. Let us first get an expression for the equation (10) within the TB-LMTO formalism of [21–23]: The basis of the LMTO starts from the minimal muffin-tin orbital basis set of a KKR formalism and then linearizes it by expanding around a ‘nodal’ energy point $E_{v\ell}^\alpha$. The wavefunction is then expanded in this basis:

$$\Phi_{jk}(\mathbf{r}) = \sum_L \sum_\alpha c_{L\alpha}^{jk} \left[\phi_{vL}^\alpha(\mathbf{r}) + \sum_{L'} \sum_{\alpha'} h_{LL'}^{\alpha\alpha'}(\mathbf{k}) \dot{\phi}_{vL'}^{\alpha'}(\mathbf{r}) \right]$$

where L is the composite angular momentum index (ℓ, m), j is the band index and α labels the atom in the unit cell; also,

$$\begin{aligned} \phi_{vL}^\alpha(\mathbf{r}) &= i^\ell Y_L(\hat{r}) \phi_\ell^\alpha(r, E_{v\ell}^\alpha) \\ \dot{\phi}_{vL}^\alpha(\mathbf{r}) &= i^\ell Y_L(\hat{r}) \frac{\partial \phi_\ell^\alpha(r, E_{v\ell}^\alpha)}{\partial E} \\ h_{LL'}^{\alpha\alpha'}(\mathbf{k}) &= (C_L^\alpha - E_{v\ell}^\alpha) \delta_{LL'} \delta_{\alpha\alpha'} + \sqrt{\Delta_L^\alpha} S_{LL'}^{\alpha\alpha'}(\mathbf{k}) \sqrt{\Delta_{L'}^{\alpha'}}. \end{aligned}$$

C_L^α and Δ_L^α are TB-LMTO potential parameters and $S_{LL'}^{\alpha\alpha'}(\mathbf{k})$ is the structure matrix. These terms are standard for the LMTO formulation and the reader is referred to [21] for greater detail. The TB-LMTO secular equation provides the expansion coefficients $c_{L\alpha}^{jk}$ via

$$\sum_{L'} \sum_{\alpha'} [h_{LL'}^{\alpha\alpha'}(\mathbf{k}) + (E_{v\ell}^\alpha - E^{jk}) \delta_{LL'} \delta_{\alpha\alpha'}] c_{L\alpha}^{jk} = 0. \quad (12)$$

We may now immediately write out an expression for the matrix element of the current operator as in equation (9):

$$\begin{aligned} \langle \Phi_{j'k}(\mathbf{r}) | j | \Phi_{jk}(\mathbf{r}) \rangle &= \sum_{LL'} \sum_\alpha \bar{c}_{L'\alpha}^{j'k} c_{L\alpha}^{jk} \{ \langle \phi_{vL'}^\alpha(\mathbf{r}) | j | \phi_{vL}^\alpha(\mathbf{r}) \rangle \cdots \\ &\cdots + (E^{jk} - E_{v\ell}^\alpha) \langle \phi_{vL'}^\alpha(\mathbf{r}) | j | \dot{\phi}_{vL}^\alpha(\mathbf{r}) \rangle \cdots \\ &\cdots + (E^{j'k} - E_{v\ell'}^{\alpha'}) \langle \dot{\phi}_{vL'}^{\alpha'}(\mathbf{r}) | j | \phi_{vL}^\alpha(\mathbf{r}) \rangle \cdots \\ &\cdots + (E^{jk} - E_{v\ell}^\alpha) (E^{j'k} - E_{v\ell'}^{\alpha'}) \langle \dot{\phi}_{vL'}^{\alpha'}(\mathbf{r}) | j | \dot{\phi}_{vL}^\alpha(\mathbf{r}) \rangle \}. \end{aligned} \quad (13)$$

We shall now obtain expressions for the right-hand terms by noting the following:

$$\mathbf{j} = e \frac{d\mathbf{r}}{dt} = \frac{e}{i\hbar} [\mathbf{r}, H] \quad H \phi_{vL}^\alpha(\mathbf{r}) = E_{v\ell}^\alpha \phi_{vL}^\alpha(\mathbf{r}) \quad H \dot{\phi}_{vL}^\alpha(\mathbf{r}) = \dot{\phi}_{vL}^\alpha(\mathbf{r}) + E_{v\ell}^\alpha \dot{\phi}_{vL}^\alpha(\mathbf{r}). \quad (14)$$

We can write

$$\mathbf{r} = (2\pi/3)^{1/2} r [(Y_{1,-1} - Y_{1,1}) \hat{\mathbf{i}} + i(Y_{1,-1} + Y_{1,1}) \hat{\mathbf{j}} + 2^{1/2} Y_{1,0} \hat{\mathbf{k}}].$$

Using the above two equations we get

$$\int \phi_{vL'}^\alpha(\mathbf{r})^* \mathbf{r} H \phi_{vL}^\alpha(\mathbf{r}) d^3\mathbf{r} = i^{\ell-\ell'} E_{v\ell}^\alpha \Gamma_{LL'} \int_0^{s_\alpha} \phi_{v\ell'}^\alpha(r) \phi_{v\ell}^\alpha(r) r^3 dr \quad (15)$$

where s_α is the atomic sphere radius of the α th atom in the unit cell and $\Gamma_{LL'}$ is a combination of Gaunt coefficients [32]:

$$\Gamma_{LL'} = \sqrt{(2\pi/3)} [(G_{\ell',1,\ell}^{m',-1,m} - G_{\ell',1,\ell}^{m',1,m}) \hat{\mathbf{i}} + i(G_{\ell',1,\ell}^{m',-1,m} + G_{\ell',1,\ell}^{m',1,m}) \hat{\mathbf{j}} + \sqrt{2} G_{\ell',1,\ell}^{m',0,m} \hat{\mathbf{k}}].$$

In order to obtain $\int \phi_{vL'}^\alpha(\mathbf{r})^* H r \phi_{vL}^\alpha(\mathbf{r}) d^3\mathbf{r}$, we note that $H = (\hbar^2/2m_e)\nabla^2 + V(\mathbf{r})$, so using the second Green identity we can obtain

$$\int \phi_{vL'}^\alpha(\mathbf{r})^* H r \phi_{vL}^\alpha(\mathbf{r}) d^3\mathbf{r} = i^{\ell-\ell'} \Gamma_{LL'} \left\{ E_{v\ell'}^\alpha \int_0^{s_\alpha} \phi_{v\ell'}^\alpha(r) \phi_{v\ell}^\alpha(r) r^3 dr \dots \right. \\ \left. \dots + (\hbar^2/2m_e) s_\alpha^2 \phi_{v\ell}^\alpha(s_\alpha) \phi_{v\ell'}^\alpha(s_\alpha) (D_{v\ell'}^\alpha - D_{v\ell}^\alpha - 1) \right\}. \quad (16)$$

$D_{v\ell}^\alpha$ are the logarithmic derivatives of $\phi_{v\ell}^\alpha(r)$ at $r = s_\alpha$ and are obtained as parameters in the TB-LMTO routines. We define the following integrals:

$$\int_0^{s_\alpha} \phi_{v\ell'}^\alpha(r) \phi_{v\ell}^\alpha(r) r^3 dr = I_{\ell\ell'}^\alpha \\ \int_0^{s_\alpha} \phi_{v\ell'}^\alpha(r) \dot{\phi}_{v\ell}^\alpha(r) r^3 dr = J_{\ell\ell'}^\alpha \\ \int_0^{s_\alpha} \dot{\phi}_{v\ell'}^\alpha(r) \dot{\phi}_{v\ell}^\alpha(r) r^3 dr = K_{\ell\ell'}^\alpha$$

and use the notation

$$(\hbar^2/2m_e) s_\alpha^2 (D_{v\ell}^\alpha - D_{v\ell'}^\alpha - 1) = \mathcal{D}_{\ell\ell'}^\alpha.$$

Then the matrix elements for the current operator become

$$\mathcal{I}_{LL',\mu}^{(1)\alpha} = \langle \phi_{vL'}^\alpha(\mathbf{r}) | j_\mu | \phi_{vL}^\alpha(\mathbf{r}) \rangle = \frac{i^{\ell-\ell'-1}}{\hbar} \Gamma_{LL'}^\mu [(E_{v\ell}^\alpha - E_{v\ell'}^\alpha) I_{\ell\ell'}^\alpha - \mathcal{D}_{\ell\ell'}^\alpha \phi_{v\ell}^\alpha(s_\alpha) \phi_{v\ell'}^\alpha(s_\alpha)] \\ \mathcal{I}_{LL',\mu}^{(2)\alpha} = \langle \phi_{vL'}^\alpha(\mathbf{r}) | j_\mu | \dot{\phi}_{vL}^\alpha(\mathbf{r}) \rangle \\ = \frac{i^{\ell-\ell'-1}}{\hbar} \Gamma_{LL'}^\mu [(E_{v\ell}^\alpha - E_{v\ell'}^\alpha) J_{\ell\ell'}^\alpha + I_{\ell\ell'}^\alpha - \mathcal{D}_{\ell\ell'}^\alpha \dot{\phi}_{v\ell}^\alpha(s_\alpha) \phi_{v\ell'}^\alpha(s_\alpha)] \\ \mathcal{I}_{LL',\mu}^{(3)\alpha} = \langle \dot{\phi}_{vL'}^\alpha(\mathbf{r}) | j_\mu | \phi_{vL}^\alpha(\mathbf{r}) \rangle \\ = \frac{i^{\ell-\ell'-1}}{\hbar} \Gamma_{LL'}^\mu [(E_{v\ell}^\alpha - E_{v\ell'}^\alpha) J_{\ell\ell'}^\alpha - I_{\ell\ell'}^\alpha - \mathcal{D}_{\ell\ell'}^\alpha \phi_{v\ell}^\alpha(s_\alpha) \dot{\phi}_{v\ell'}^\alpha(s_\alpha)] \\ \mathcal{I}_{LL',\mu}^{(4)\alpha} = \langle \dot{\phi}_{vL'}^\alpha(\mathbf{r}) | j_\mu | \dot{\phi}_{vL}^\alpha(\mathbf{r}) \rangle = \frac{i^{\ell-\ell'-1}}{\hbar} \Gamma_{LL'}^\mu [(E_{v\ell}^\alpha - E_{v\ell'}^\alpha) K_{\ell\ell'}^\alpha + J_{\ell\ell'}^\alpha - J_{\ell\ell'}^\alpha \dots \\ \dots - \mathcal{D}_{\ell\ell'}^\alpha \dot{\phi}_{v\ell}^\alpha(s_\alpha) \dot{\phi}_{v\ell'}^\alpha(s_\alpha)]. \quad (17)$$

The transition term $T^{jj'}(\mathbf{k})$ has to be written in terms of the normalized wavefunction. The normalizing factors for the wavefunctions are obtained from

$$N_k^j = \int d^3\mathbf{r} \Phi_{jk}^*(\mathbf{r}) \Phi_{jk}(\mathbf{r}) = \sum_L \sum_\alpha |\tilde{c}_{L\alpha}^{jk}|^2 \{ \mathcal{J}_{L\alpha}^{(1)} + 2(E^{jk} - E_{v\ell}^\alpha) \mathcal{J}_{L\alpha}^{(2)} + (E^{jk} - E_{v\ell}^\alpha)^2 \mathcal{J}_{L\alpha}^{(3)} \} \quad (18)$$

where

$$\mathcal{J}_{L\alpha}^{(1)} = \int_0^{s_\alpha} |\phi_{vL}^\alpha(r)|^2 r^2 dr \\ \mathcal{J}_{L\alpha}^{(2)} = \int_0^{s_\alpha} \phi_{vL}^\alpha(r)^* \dot{\phi}_{vL}^\alpha(r) r^2 dr \\ \mathcal{J}_{L\alpha}^{(3)} = \int_0^{s_\alpha} |\dot{\phi}_{vL}^\alpha(r)|^2 r^2 dr.$$

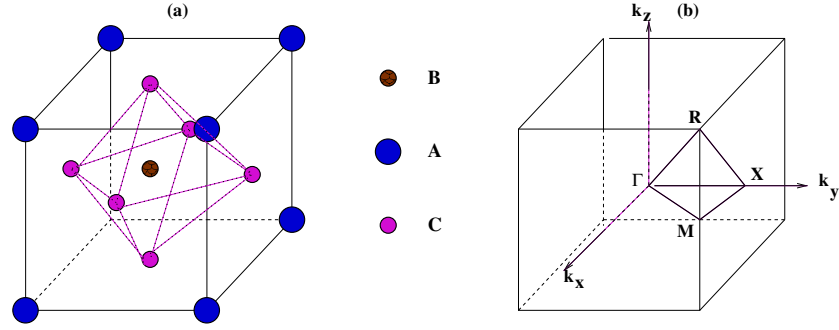


Figure 1. (a) The cubic unit cell for a perovskite ABC_3 . (b) The Brillouin zone for the cubic phase. (This figure is in colour only in the electronic version)

Using the secular equation (12), the expression for the transition term becomes

$$T^{jj'}(\mathbf{k}) = (N_k^j N_k^{j'})^{-1/2} \left| \sum_{\mu} \sum_{LL'} \sum_{\alpha} \bar{c}_{L'\alpha}^{j'k} c_{L\alpha}^{jk} \{ \mathcal{I}_{LL',\mu}^{(1)\alpha} + (E^{jk} - E_{v\ell}^{\alpha}) \mathcal{I}_{LL',\mu}^{(2)\alpha} \dots \dots + (E^{j'k} - E_{v\ell'}^{\alpha}) \mathcal{I}_{LL',\mu}^{(3)\alpha} + (E^{jk} - E_{v\ell}^{\alpha})(E^{j'k} - E_{v\ell'}^{\alpha}) \mathcal{I}_{LL',\mu}^{(4)\alpha} \} \right|^2. \quad (19)$$

Equation (10) provides an expression for the optical conductivity where both the transition matrix and the energy-resolved joint density of states are expressed as functions of energy and frequency. As we shall show in a subsequent communication, within the ASR formalism this is the form in which the information about the constituents are input, and the configuration averaged correlation function for the alloy may be expressed as

$$\langle\langle S(\omega) \rangle\rangle = (\pi/3) \int dE T^{eff}(E, \omega) \langle\langle J(E, \omega) \rangle\rangle \quad (20)$$

where

$$\langle\langle J(E, \omega) \rangle\rangle = \langle\langle n_v(E) \rangle\rangle \langle\langle n_c(E + \omega) \rangle\rangle [1 + \Lambda(E, \omega) \langle\langle J(E, \omega) \rangle\rangle]$$

and

$$T^{eff}(E, \omega) = \langle\langle T(E, \omega) \rangle\rangle + \delta T(E, \omega, \Sigma(E, \omega))$$

where $\Sigma(E, \omega)$ is the self-energy due to disorder scattering and $\Lambda(E, \omega)$ the corresponding vertex correction. The details of the derivation will be communicated in a subsequent paper [24].

3. Computational details and results

The primitive cell for the ideal perovskite structure ABC_3 is illustrated in figure 1(a). For the class of compounds that we are interested in, the generic chemical formula is ABO_3 . A is a monovalent or divalent cation; B is a tetravalent or pentavalent metal. In the paraelectric phase there is full cubic symmetry. It can be thought of as a lattice of corner-sharing oxygen octahedra with interpenetrating simple cubic lattices of A and B. The B cations sit at the centres of the octahedral O cages, while the A metal ions sit in the 12-fold-coordinated sites between the octahedra. In our case the body-centre position is occupied by the Ti atom, the edges by alkaline-earth atoms and the face centres by O atoms. The space group is O_h^1 and the

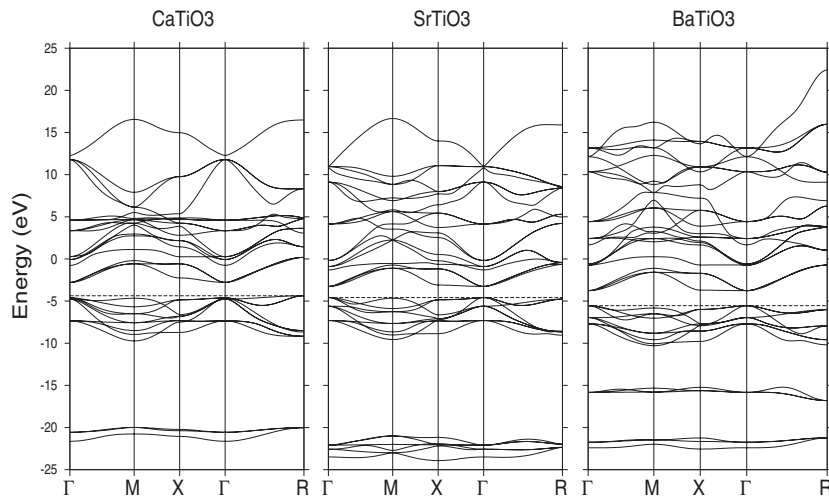


Figure 2. Band structures of CaTiO_3 , SrTiO_3 and BaTiO_3 (no scissors operation has been carried out on these calculations).

Table 1. Electronic configurations of the alkaline-earth atoms.

Atom	Deep core	Shallow core	Valence	Unoccupied
Ca	$1s^2 2s^2 2p^6 3s^2 3p^6$	—	$4s^2$	$3d 4p$
Sr	$1s^2 2s^2 2p^6 3s^2 3p^6 3d^{10} 4s^2$	$4p^6$	$5s^2$	$4d 5p 4f$
Ba	$1s^2 2s^2 2p^6 3s^2 3p^6 3d^{10} 4s^2 4p^6 4d^{10} 5s^2$	$5p^6$	$6s^2$	$5d 6p 4f$
Ti	$1s^2 2s^2 2p^6 3s^2 3p^6$	—	$3d^2 4s^2$	$4p$
O	$1s^2$	—	$2s^2 2p^4$	$3s 3d$

corresponding Brillouin zone is shown in figure 1(b). Both the A and B atoms are situated at sites with full cubic (O_h) point symmetry, while the O atoms have tetragonal (D_{4h}) symmetry.

The electronic configurations of the alkaline-earth atoms are shown in table 1.

Since we wish to take into account the shallow core states, to include the transitions from these to the conduction band at large enough optical frequencies, the energy range is about 40 eV (3 Ryd) and the single-panel LMTO cannot be made to be accurate over this range, we have carried out a two-panel calculation, with the $E_{v\ell}^\alpha$ lying in the lower energy range in one panel and in the upper energy range in the other. The minimal basis sets used in the two panels are shown in table 2.

The states in parentheses are unfilled states which have been downfolded in our calculations. Figure 2 shows the band structures of the three titanates.

Let us first look at the leftmost figure for CaTiO_3 . The Ca 3p core level lies around -27 eV and is not shown in this figure. The narrow band around -20 eV is the O 2s band. The nine valence bands just below the Fermi level are derived from hybridized Ti 4s and O 2p. An indirect band gap appears between the valence band top at the R point and the conduction band minimum at the Γ point. CaTiO_3 shows an indirect band gap (Γ -R) of 1.6 eV, in the absence of the *scissors* operation. The experimentally reported indirect gap is 3.5 eV [25]. This discrepancy is characteristic of the LDA upon which the TB-LMTO is based. In the conduction band region we have bands originating from (in ascending order of energy) a Ti $3d-t_{2g}$ triplet, a singlet arising from Ca 4s and a doublet arising from Ti $3d-e_g$. Then come the

Table 2. The minimal basis sets used in the lower and upper energy panels.

CaTiO ₃	
Lower panel	Ca 4s 4p 3d, Ti 4s 4p 3d, O 2s 2p (3d)
Upper panel	Ca 4s 4p 3d, Ti 4s 4p 3d, O 3s 2p (3d)
SrTiO ₃	
Lower panel	Sr 5s 4p 4d (4f), Ti 4s 4p 3d, O 2s 2p (3d)
Upper panel	Sr 5s 5p 4d (4f), Ti 4s 4p 3d, O 3s 2p (3d)
BaTiO ₃	
Lower panel	Ba 6s 5p 5d (4f), Ti 4s 4p 3d, O 2s 2p (3d)
Upper panel	Ba 6s 6p 3d (4f), Ti 4s 4p 3d, O 3s 2p (3d)

bands which originate from the Ca 3d- e_g doublet and the Ca 3d- t_{2g} triplet. Finally we have the Ti 4p- and Ca 4p-based bands and finally the band based on Ca 4s. We note that for CaTiO₃, Ca- and Ti 3d-based bands overlap and hybridize in the conduction region.

For SrTiO₃, in the lower panel, the Sr 4p level now sits almost atop the O 2s band, giving rise to a rather broad (as compared to CaTiO₃) s-p hybridized band just below -20 eV. The subsequent analysis of the bands is rather similar to that of CaTiO₃. However, the band gap is now direct and ~1.4 eV. Earlier band-structure calculations by Mo *et al* [33] and Kimura *et al* [34] yield indirect band gaps of ~1.45 and ~1.79 eV respectively. The experimental direct band gap is around 3.2 eV.

For BaTiO₃, in the lower panel, the Ba 5p shallow core level now crosses and lies above the O 2s band. The band gap is direct and ~1.2 eV. The band structure is almost identical to the pseudopotential calculation of King-Smith and Vanderbilt [20], whose band gap was also direct and ~1.8 eV. The experimental band gap turns out to be ~3.2 eV [35].

For all three compounds, our calculations show a characteristic flatness of the lowest conduction band along Γ to X. This agrees with earlier works of Cardona [36], Mattheiss [10], Harrison [37], Wolfram and Ellialtıođlu [38] and King-Smith and Vanderbilt [20]. This observed flatness is related to certain unusual features in the density of states and optical conductivity, which appear to be characteristic of pseudo-two-dimensional systems.

Figure 3 shows the densities of states for the three titanates. The densities of states reflect the detailed band structure that we have described above. Earlier works on the density of states were based on different methods. Michel-Calendini and Mesnard [7, 8] and Pertosa and Michel-Calendini [13] have used parametrized tight-binding and adjusted LCAO-based methods for BaTiO₃. Their density of states is in agreement with ours, with the band-gap difference characteristic of LSDA methods like the TB-LMTO. Similarly, Mattheiss [10] used the LCAO and Perkins and Winter [14] used the extended Hückel basis for SrTiO₃. Again their band structures and densities of states are in agreement with ours, with the exception of the band gap. Even earlier works on SrTiO₃ by Zook and Casselman [15] and Soules *et al* [16] also show reasonable agreement. For CaTiO₃ we may compare our results with those of Ueda *et al* [25]; they agree reasonably well.

Figure 4 displays the transition rates $T(E, \omega)$ for the three titanates, shown here as functions of the initial energy of the excited electron and the incident photon energy (frequency). It is clear from the figure that the transition rate is strongly dependent on the energy-frequency variables for all three compounds. The usual assumption of a transition matrix weakly dependent on energy and frequency is certainly not valid in any of the three cases [39–41].

In figure 5 we compare the imaginary part of the dielectric function with the scaled joint density of states/ ω^2 . If the transition rate was independent of energy and frequency, they should

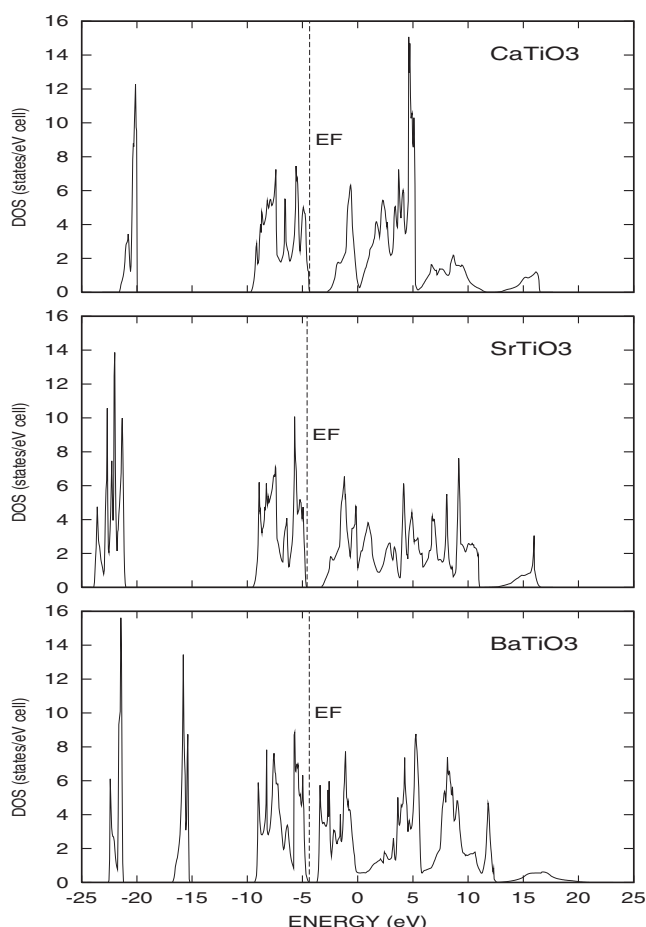


Figure 3. Densities of states for the three perovskite titanates.

be the same. The behaviours of the two are similar, but the relative weights of the structures across the frequency range are clear indications of the energy–frequency dependence of the transition rates.

CaTiO₃. The effect of the energy–frequency dependence of the transition rate has a large effect on the optical properties of *CaTiO₃*. If we compare the results reported in [41] with our figure 6, we note that although in the earlier work the joint density of states does reproduce the peaks at lower frequencies, the relative heights are not replicated. Looking at the lower panel of the figure, we may assign the peak at 4.5 eV to the transitions: $O\ 2p \rightarrow Ti\ 3d-t_{2g}$ at the R and X points. The next and highest peak arises because of the two nearby unresolved peaks due to the transitions $O\ 2p \rightarrow Ca\ 4s$ at the M point (at 6.3 eV) and $O\ 2p \rightarrow Ca\ 3d-e_g$ at the M point (at 6.8 eV). The third peak at 7.5 eV may be assigned to the transitions $O\ 2p \rightarrow Ti\ 3d-t_{2g}$ at the R point and $O\ 2p \rightarrow Ca\ 3d-e_g$ at the X point. At higher frequencies, the theory does not tally well with experiment. The peak at 10 eV is not reproduced except as a shoulder. The real part of the dielectric function $\varepsilon_1(\omega)$ is obtained by a Kramers–Krönig transformation from the imaginary part. This is shown in the top panel of figure 6. The discrepancies at high frequencies

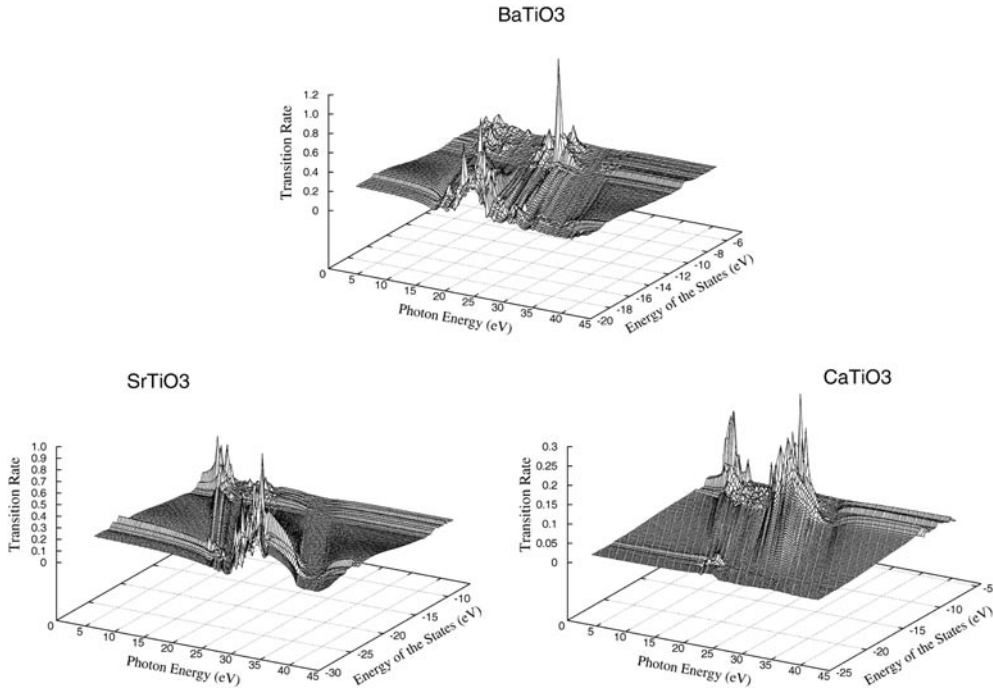


Figure 4. Transition rates for the three perovskite titanates shown as functions of initial energies and incident photon energies.

could be due to the fact that in the scissors-type approach we have provided a rigid shift to the conduction bands. In a fully fledged many-body GW technique, which it is our ultimate aim to produce, the shift due to the self-energy will turn out to be energy (frequency) dependent.

SrTiO₃. Let us now examine figure 7. As in the case of *CaTiO₃*, here too the effect of the energy–frequency dependence of the transition rate leads to the correct relative heights of the peaks in $\varepsilon_2(\omega)$ being reproduced. The shoulder peak at around 4 eV may be attributed to the transitions $O\ 2p \rightarrow Ti\ 3d-t_{2g}$ and $O\ 2p \rightarrow Ti\ 3d-e_g$ both at the Γ point. The high peak at 5 eV is due to the $O\ 2p \rightarrow Ti\ 3d-e_g$ transition at the Γ point. A third shoulder peak at 6 eV is due to the transition $O\ 2p \rightarrow Ti\ 3d-e_g$, also at the Γ point. As in the case of *CaTiO₃*, the structure in the high-frequency part has both peaks lower and shifted to higher frequencies. The cause is the same as that discussed above.

BaTiO₃. Lastly, let us look at figures 6–8. If we compare the shape of the imaginary part of the dielectric function $\varepsilon_2(\omega)$ obtained by our accurate estimate of the transition rate with that of [41], we note that agreement with experiment [42] is much better when we take the energy–frequency dependences of the transition matrix into account. The relative weights of the low-frequency peaks at 3.8 and 5 eV are correctly reproduced here. The lower peak is attributed to the transition from the $O\ 2p$ to the $Ti\ 3d-t_{2g}$ band and from the $O\ 2p$ to the $Ti\ 3d-e_g$ band, both at the Γ points. The next-highest peak is there because of the transition from the $O\ 2p$ to the $Ti\ 3d-e_g$ band at the Γ point. Our present study also indicates a peak around 10 eV, and the features at higher frequencies follow the experimental results closely, although the amplitude seems to have been underestimated as compared to the low-frequency results.

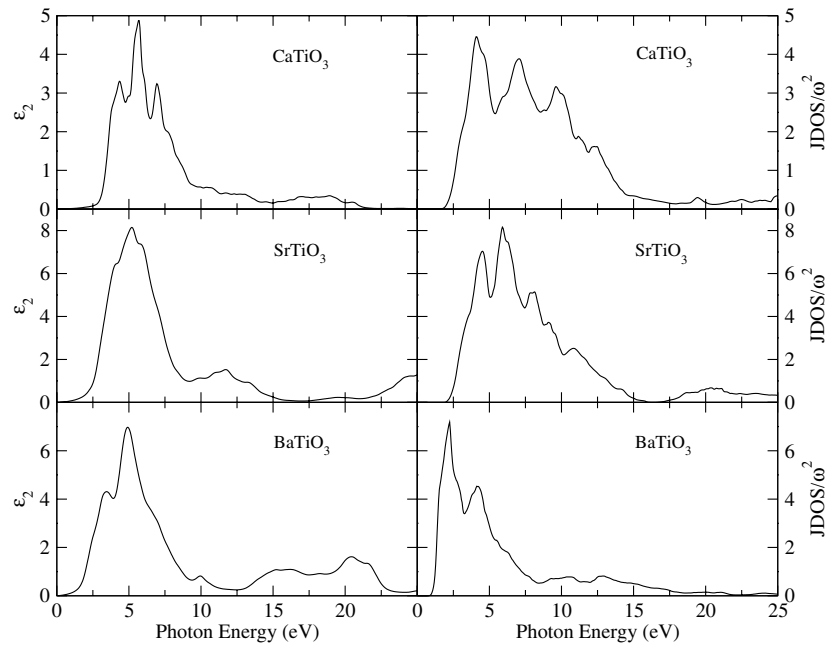


Figure 5. Comparison of the calculated imaginary part of the dielectric function (ϵ_2) (left), for the three perovskite titanates, with the same function calculated considering the transition rate to be constant (right).

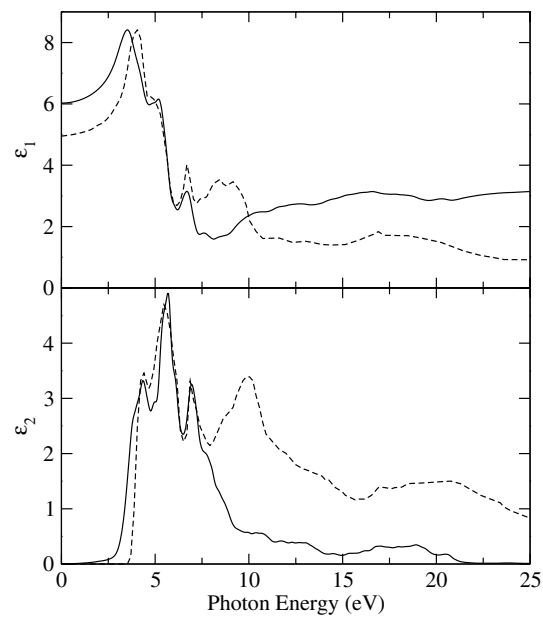


Figure 6. Comparison of calculated and experimental real parts $\epsilon_1(\omega)$ (top) and imaginary parts $\epsilon_2(\omega)$ (bottom) of the dielectric function of CaTiO₃ as a function of the photon energy: the dotted curve is experimental [25, 26]; the continuous curve is theoretical.

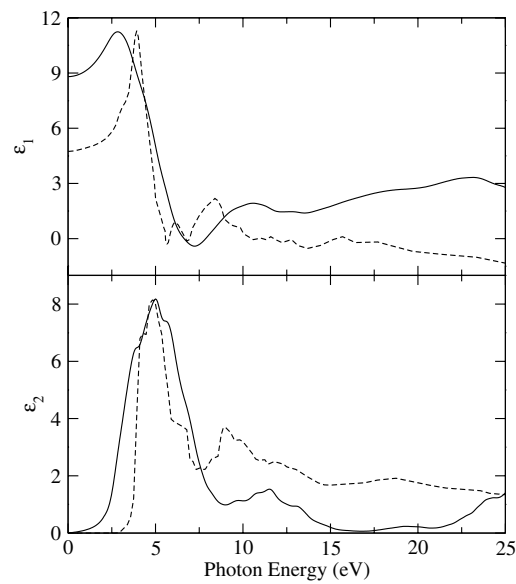


Figure 7. Comparison of the calculated and experimental real parts $\epsilon_1(\omega)$ (top) and imaginary parts $\epsilon_2(\omega)$ (bottom) of the dielectric function of SrTiO₃ as a function of the photon energy: the dotted curve is experimental [42]; the continuous curve is theoretical.

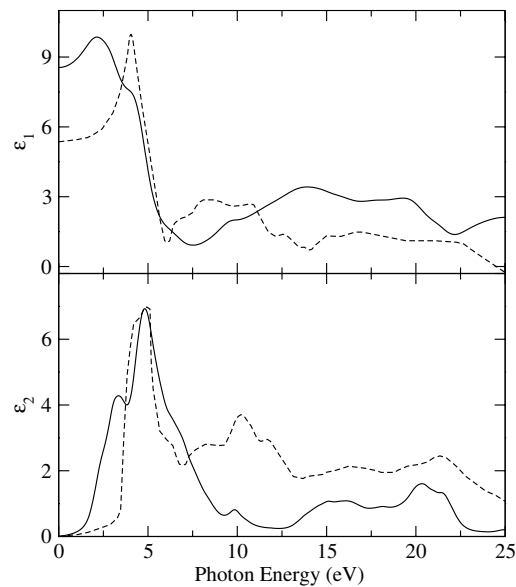


Figure 8. Comparison of calculated and experimental real parts $\epsilon_1(\omega)$ (top) and imaginary parts $\epsilon_2(\omega)$ (bottom) of the dielectric function of BaTiO₃ as a function of the photon energy: the dotted curve is experimental (see [42]); the continuous curve is theoretical.

In all cases, although the lower-frequency part is much better reproduced, the high-frequency structures in the theoretical result are shifted upwards. As before, we argue that this is probably an artifact of the rigid shift of the scissors-type approach. An energy–frequency dependent self-energy of the type given by the *GW* method should provide the necessary correction.

In addition, the wrong heights at higher frequencies could also arise from the fact that we have neglected transitions to some of the higher-energy conduction bands. A more complete (perhaps three-panel) calculation at higher energies should correct this. Alternatively, we could use the higher-order NMTOs [43], when they are available, since they span a much larger energy range.

4. Conclusions

We have proposed here a modified expression for the optical conductivity as a convolution of an energy–frequency dependent transition matrix and the energy-resolved joint density of states. The main motivation was to generalize it to disordered systems, where the traditional reciprocal space formulation breaks down due to the failure of Bloch’s theorem. In order to gain confidence in our new formulation we have applied it here to the three alkaline-earth perovskite titanates in their paraelectric phases. The results are in reasonable agreement with experimental data. The agreement is as good as we can expect from a LDA calculation. This formulation will now form the starting point of a twofold generalization: first, combining with the ASR for application to random systems and then as a starting point for a many-body *GW* formulation.

References

- [1] Mookerjee A 1973 *J. Phys. C: Solid State Phys.* **6** 1340
- [2] Kaplan T and Gray L J 1977 *Phys. Rev. B* **15** 3260
- [3] Saha T, Dasgupta I and Mookerjee A 1996 *J. Phys.: Condens. Matter* **8** 1979
- [4] Dasgupta I, Saha T and Mookerjee A 1997 *J. Phys.: Condens. Matter* **9** 3529
- [5] Ghosh S, Das N and Mookerjee A 1999 *Int. J. Mod. Phys. B* **21** 723
- [6] Castet-Mejean L 1986 *J. Phys. C: Solid State Phys.* **19** 1637
- [7] Michel-Calendini M and Mesnard G 1971 *Phys. Status Solidi* **44** K117
- [8] Michel-Calendini M and Mesnard G 1973 *J. Phys. C: Solid State Phys.* **6** 1709
- [9] Kahn A H and Leyendecker A J 1964 *Phys. Rev. A* **135** 1321
- [10] Mattheiss L F 1972 *Phys. Rev. B* **6** 4718
- [11] Soules T F, Kelly E J, Vaught D M and Richardson J W 1972 *Phys. Rev. B* **6** 1519
- [12] Battaye F L, Hochst H and Goldmann A 1976 *Solid State Commun.* **19** 269
- [13] Pertosa P and Michel-Calendini F M 1978 *Phys. Rev.* **17** 2011
- [14] Perkins P G and Winter D M 1983 *J. Phys. C: Solid State Phys.* **16** 3481
- [15] Zook D J and Casselman T M 1975 *Surf. Sci.* **37** 244
- [16] Soules T F, Kelly E J, Vaught D M and Richardson J W 1972 *Phys. Rev. B* **6** 1519
- [17] Cohen R E and Krakauer H 1990 *Phys. Rev. B* **42** 6416
Cohen R E and Krakauer H 1992 *Ferroelectrics* **136** 65
- [18] Cohen R E 1992 *Nature* **358** 136
- [19] Singh D J and Boyer L L 1992 *Ferroelectrics* **136** 95
- [20] King-Smith R D and Vanderbilt D 1994 *Phys. Rev. B* **49** 5828
King-Smith R D and Vanderbilt D 1992 *Ferroelectrics* **136** 85
- [21] Andersen O K 1975 *Phys. Rev. B* **12** 3060
- [22] Jepsen O and Andersen O K 1971 *Solid State Commun.* **9** 1763
- [23] Skriver H L 1984 *The LMTO Method: Muffin-Tin Orbitals and Electronic Structure* (New York: Springer)
- [24] Saha K K, Saha-Dasgupta T and Mookerjee A 2002 *J. Phys.: Condens. Matter* to be submitted
- [25] Ueda K, Yanagi H, Hosono H and Kawazoe H 1998 *J. Phys.: Condens. Matter* **10** 3669
- [26] Ueda K, Yanagi H, Hosono H and Kawazoe H 1999 *J. Phys.: Condens. Matter* **11** 3535
- [27] Uspenski Yu A, Maksimov E G, Rashkeev S N and Mazin I I 1983 *Z. Phys. B* **53** 263
- [28] Alouani M, Koch J M and Khan M A 1986 *J. Phys. F: Met. Phys.* **16** 473
- [29] Alouani M, Brey L and Christensen NE 1988 *Phys. Rev. B* **37** 1167
- [30] Zemach R, Ashkenazi J and Ehrenfreund E 1989 *Phys. Rev. B* **39** 1884
- [31] Zemach R, Ashkenazi J and Ehrenfreund E 1989 *Phys. Rev. B* **39** 1891

- [32] Hobbs D, Piparo E, Girlanda R and Monaca M 1995 *J. Phys.: Condens. Matter* **7** 2541
- [33] Mo S D, Ching W Y, Chisholm M F and Duscher G 1999 *Phys. Rev. B* **60** 2416
- [34] Kimura S, Yamaguchi Y, Tsukada M and Watanabe S 1995 *Phys. Rev. B* **51** 11 049
- [35] Wemple S H 1970 *Phys. Rev. B* **2** 2679
- [36] Cardona M 1965 *Phys. Rev.* **146** A651
- [37] Harrison W A 1989 *Electronic Structure and the Properties of Solids* (New York: Dover) ch 19
- [38] Wolfram T and Ellialtıođlu Ő 1977 *Phys. Rev. B* **15** 5909
Wolfram T and Ellialtıođlu Ő 1982 *Phys. Rev. B* **25** 2697
- [39] Saha S, Sinha T P and Mookerjee A 2000 *Phys. Rev. B* **62** 8828
- [40] Saha S, Sinha T P and Mookerjee A 2000 *J. Phys.: Condens. Matter* **12** 3325
- [41] Saha S, Sinha T P and Mookerjee A 2000 *Eur. Phys. J. B* **18** 207
- [42] Bauerle D, Braun W, Saile V, Sprussel G and Koch E E 1978 *Z. Phys. B* **29** 179
- [43] Andersen O K and Saha-Dasgupta T 2000 *Phys. Rev. B* **62** R16 219